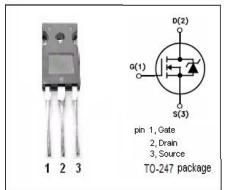


isc N-Channel MOSFET Transistor

FDH50N50

• FEATURES

- · With TO-247 packaging
- With low gate drive requirements
- · Easy to drive
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



APPLICATIONS

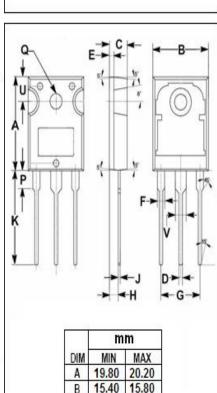
· Switching applications



SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	500	V
V _{GSS}	Gate-Source Voltage	±20	V
I _D	Drain Current-Continuous	48	Α
I _{DM}	Drain Current-Single Pulsed	192	А
P_D	Total Dissipation	625	W
Tj	Operating Junction Temperature	-55~150	°C
T _{stg}	Storage Temperature	-55~150	°C

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.2	°C/W



	mm	
DIM	MIN	MAX
Α	19.80	20.20
В	15.40	15.80
C	4.90	5.10
D	0.90	1.10
E	1.40	1.60
F	1.90	2.10
G	10.80	11.00
Н	2.40	2.60
J	0.50	0.70
K	19.50	20.50
P	3.90	4.10
Q	3.30	3.50
U	5.20	5.40
٧	2.90	3.10

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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	500			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.25mA	3.0		5.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =24A		89	105	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} = 0V			±0.1	μА
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 500V; V _{GS} = 0V;@Tc=25°C V _{DS} = 400V; V _{GS} = 0V;Tc=125°C			25 250	μ А
V_{SDF}	Diode forward voltage	I _{SD} =48A, V _{GS} = 0V			1.4	V



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